

1 **Molecular beam epitaxy of $\text{Co}_x\text{Fe}_{4-x}\text{N}$ ($0.4 < x < 2.9$) thin films on $\text{SrTiO}_3(001)$ substrates**

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6

7 **Abstract**

8 We attempted to grow $\text{Co}_x\text{Fe}_{4-x}\text{N}$ epitaxial thin films on $\text{SrTiO}_3(001)$ substrates by molecular
9 beam epitaxy supplying solid Co and Fe and a radio frequency N_2 plasma, simultaneously.

10 The composition ratio of Co/Fe in $\text{Co}_x\text{Fe}_{4-x}\text{N}$ was controlled by changing the weight ratio of
11 Co to Fe flakes in the crucible of the Knudsen cell used. We confirmed epitaxial growth of
12 $\text{Co}_x\text{Fe}_{4-x}\text{N}$ ($0.4 < x < 2.9$) thin films by reflection high-energy electron diffraction and θ - 2θ
13 X-ray diffraction patterns. The in-plane lattice parameter of the $\text{Co}_x\text{Fe}_{4-x}\text{N}$ films was almost
14 the same as the out-of-plane lattice parameter, and they decreased with increasing Co
15 composition, following Vegard's law.

16

17 *Keywords:* A3.Molecular beam epitaxy, B2.Ferromagnetic materials, B1. $\text{Co}_x\text{Fe}_{4-x}\text{N}$,
18 B1. SrTiO_3

19

20 **1. Introduction**

21 Highly spin-polarized ferromagnetic materials have attracted increasing attention for
22 high-performance spintronics devices such as the read heads of hard disc drives and spin
23 random access memory. For these materials, special attention has been focused on cubic
24 perovskite 3d ferromagnetic nitrides such as Fe₄N and Co₄N. The spin asymmetry $\beta = (\sigma_{\uparrow} -$
25 $\sigma_{\downarrow})/(\sigma_{\uparrow} + \sigma_{\downarrow})$ of Fe₄N was calculated to be -1.0 [1], and we evaluated $|\beta|$ to be 0.59 at 7.8 K
26 by means of point contact Andreev reflection measurement [2]. There have been a few reports
27 on the inverse tunnel magnetoresistance of -75% in CoFeB/MgO/Fe₄N magnetic tunnel
28 junctions and negative anisotropic magnetoresistance in Fe₄N films at room temperature [3-6].
29 The spin-resolved density of states (D) in Co₄N was calculated [7,8], and spin polarization P
30 $= (D_{\uparrow} - D_{\downarrow})/(D_{\uparrow} + D_{\downarrow})$ at the Fermi level was estimated to be -0.88 by Imai *et al.*, which
31 exceeds that in Fe₄N of -0.67 [8]. We have already succeeded in epitaxial growth of Fe₄N and
32 Co₄N thin films on SrTiO₃(STO)(001) substrates by molecular beam epitaxy (MBE) [9,10]
33 and we evaluated the spin and orbital magnetic moments by X-ray magnetic circular
34 dichroism [11,12]. Recent first-principles calculation indicating that P was estimated to be
35 -1.0 in Co₃FeN has renewed interest in this material [13]. There have been several reports on
36 perovskite mixed crystal nitrides such as (Co,Fe)₄N and (Mn,Fe)₄N. H. Y. Wang *et al.* formed
37 CoFeN films by radio frequency (RF) magnetron sputtering and evaluated their magnetic
38 anisotropy [14-16]. First-principles calculations were performed for the electronic and

39 magnetic structures in $(\text{Mn,Fe})_4\text{N}$ [17-20]. D. L. Peng *et al.* characterized perpendicular
40 magnetic anisotropy of $(\text{Fe,Cr})_4\text{N}_x$ films formed by DC magnetron sputtering [21-23].
41 However, there have been no reports so far on epitaxial growth of $(\text{Co,Fe})_4\text{N}$ thin films. In
42 order to apply $(\text{Co,Fe})_4\text{N}$ films to spintronics devices, characterization of the basic material
43 properties of high quality $(\text{Co,Fe})_4\text{N}$ films is required. In this study, we attempted to grow
44 $(\text{Co,Fe})_4\text{N}$ epitaxial films on STO(001) substrates by MBE, while varying the composition
45 ratio of Co/Fe in $(\text{Co,Fe})_4\text{N}$.

46

47 **2. Experimental procedures**

48 Approximately 25-nm-thick $(\text{Co,Fe})_4\text{N}$ thin films were grown on STO(001) substrates
49 by supplying Co, Fe and N atoms simultaneously using an ion-pumped MBE system equipped
50 with a high-temperature Knudsen cell for Co and Fe, and an RF- N_2 plasma for N [9,10]. The
51 lattice mismatch between Fe_4N and STO is 2.8%, and that between Co_4N and STO is 4.3%.
52 Co and Fe flakes were placed into the same crucible. Various weight ratios of Co/Fe in the
53 crucible were used including 0.5:1 (sample A), 1:1 (sample B), 3:1 (sample C) and 5.6:1
54 (sample D). During the growth of these samples, the temperature of the STO substrate was
55 kept at 450 °C, and the deposition rate of Co plus Fe was set to be approximately 0.5 nm/min.
56 The flow rate of the N_2 gas was fixed at 1.0 sccm, and the input power to the RF plasma was
57 140 W. The pressure inside the chamber was approximately 1×10^{-4} Torr during film growth.

58 The crystalline quality of samples A-D was evaluated by reflection high-energy electron
59 diffraction (RHEED) and θ - 2θ X-ray diffraction (XRD). We deduced the lattice constants of
60 samples along directions perpendicular and parallel to the substrate surface from out-of-plane
61 and in-plane θ - 2θ XRD patterns, respectively. The composition ratio of Co/Fe in the films
62 was determined by energy dispersive X-ray spectroscopy (EDX) using an accelerating voltage
63 of 10 kV with a spot size of 30 μm and by Rutherford back scattering spectrometry (RBS)
64 using a He ion beam with an acceleration voltage of 2.3 MeV.

65

66 **3. Results and discussion**

67 Figures 1(a)-1(d) show the RHEED patterns of samples A-D, respectively. Streaky
68 RHEED patterns were obtained except for the spotty pattern for sample B. Figure 2(a) shows
69 the out-of-plane θ - 2θ XRD patterns of $\text{Fe}_4\text{N}/\text{STO}(001)$, and Figs. 2(b)-2(e) show those of
70 samples A-D, respectively. In samples A-D, the diffraction peaks of $(\text{Co,Fe})_4\text{N}(001)$, (002)
71 and (004) were observed. With increasing weight ratio of Co to Fe in the crucible, these
72 peaks shifted to a higher angle. Figures 3(a)-3(d) show the in-plane θ - 2θ XRD patterns of
73 samples A-D around $2\theta=23^\circ$, respectively. The diffraction peaks of $(\text{Co,Fe})_4\text{N}(100)$ were
74 clearly observed in these samples. With increasing weight ratio of Co to Fe in the crucible,
75 these peaks also shifted to a higher angle. According to the X-ray extinction law, the
76 diffraction peak of fcc-Co(100) is forbidden; however, that of $(\text{Co,Fe})_4\text{N}(100)$ is allowed.

77 The experimentally obtained intensity ratios of (100) to (200) were 0.0096, 0.0092, 0.0074,
78 and 0.0079, in samples A-D, respectively. In the case of Co_4N , the intensity ratio is
79 theoretically estimated to be 0.027. Therefore, we can state that the grown layers are not
80 fcc-Co, but $(\text{Co,Fe})_4\text{N}$ in which N atom is located at the body center of the unit cell. On the
81 basis of these results, we confirmed that the $(\text{Co,Fe})_4\text{N}$ layers grew epitaxially on the
82 STO(001) substrates. At present, we cannot determine the degree of order of N atoms. It can
83 be estimated, for example, by comparing the experimentally obtained intensity ratios of
84 (100) to (200) with theoretical ones. However, information about Fe and Co sites in the unit
85 cell of $(\text{Co,Fe})_4\text{N}$ is limited at present, and thus further studies are mandatory for this
86 estimation. A small diffraction peak of Fe(002) in Figs. 2(b)-2(e) indicate that pure Fe exists
87 in the $(\text{Co,Fe})_4\text{N}$ layers of samples A-D. However, the peak intensities were negligibly small
88 compared to those of $(\text{Co,Fe})_4\text{N}$. Thus, we consider that the analysis of the composition ratio
89 Co/Fe in the $(\text{Co,Fe})_4\text{N}$ layers of samples A-D was not affected by the existence of pure Fe,
90 if there was any present. In order to determine the Co/Fe composition ratio in the $(\text{Co,Fe})_4\text{N}$
91 layers using EDX measurements, we grew an Au(5 nm)/ $(\text{Co,Fe})_4\text{N}$ (12 nm) film on the
92 MgO(001) substrate (sample E) using the same growth procedure as sample C, and evaluated
93 the composition ratio of Co, Fe and N using RBS measurements.

94 Figure 4 shows the RBS depth profiles of Co, Fe, N, Au, Mg and O atoms in sample E.
95 The composition ratio in the $(\text{Co,Fe})_4\text{N}$ layer was evaluated to be approximately Co:Fe =

96 1.4:1.0, and (Co+Fe):N = 4:1. We assumed that the composition ratio of (Co,Fe)₄N in sample
 97 C was the same as that in sample E, and we estimated the Co/Fe ratio in sample C to be
 98 Co_{2.3}Fe_{1.7}N. Figures 5(a)-5(d) show the EDX spectra of samples A-D, respectively. Peaks of
 99 Co *K*_α (6.924 keV) and Fe *K*_β (7.057 keV) X-rays partially overlapped. We separated the
 100 overlapped peak into two peaks using Gaussian curve fitting. The integrated intensity of the
 101 Co *K*_α X-ray peak was enhanced with increasing weight ratio of Co/Fe in the crucible. On
 102 the other hand, the integrated intensity of the Fe *K*_α X-ray peak was relatively suppressed.
 103 We determined the composition ratio in the (Co,Fe)₄N layers of samples A, B and D using
 104 the RBS measurements for sample E and obtained EDX spectra of samples A-D. First, we
 105 deduced a constant value γ using

$$\frac{EDX_{CoK\alpha}}{EDX_{FeK\alpha}} = \gamma \frac{RBS_{Co}}{RBS_{Fe}}, \quad (1)$$

107 where $EDX_{CoK\alpha} / EDX_{FeK\alpha}$ is the ratio of integrated EDX intensity of Co *K*_α to Fe *K*_α
 108 X-rays in sample C, and RBS_{Co} / RBS_{Fe} is the composition ratio of Co/Fe in sample E
 109 obtained by the RBS depth profiles shown in Fig. 4. We evaluated the composition ratio of
 110 Co/Fe in (Co,Fe)₄N layers for samples A, B and D using $EDX_{CoK\alpha} / EDX_{FeK\alpha}$ of these
 111 samples divided by the constant γ to be Co_{0.4}Fe_{3.6}N, Co_{1.2}Fe_{2.8}N and Co_{2.9}Fe_{1.1}N, respectively,
 112 as summarized in Table 1.

113 Figure 6(a) shows the out-of-plan lattice constants of samples A-D deduced from
 114 (Co,Fe)₄N(002) and (Co,Fe)₄N(004) θ -2 θ XRD peak positions plotted as a function of $\cot\theta$.

115 The peak positions were determined by Gaussian fitting for the XRD patterns, and lattice
116 constants were deduced by Bragg's law. Figure 6(b) shows the out-of-plane lattice constants
117 of samples A-D after correction of the measurement error, by extrapolating from the
118 intersection of the straight line passing through the above two points at $\cot\theta = 0$ in Fig. 5(a),
119 plotted against the composition ratio of $\text{Co}_x\text{Fe}_{4-x}\text{N}$. A dashed line is drawn for Vegard's law
120 [24] using the bulk lattice constants of Fe_4N (0.3796 nm) [25] and Co_4N (0.3738 nm) [26].
121 The out-of-plane lattice constants of samples A-D were 0.3793, 0.3768, 0.3761 and 0.3750
122 nm, respectively. Figures 7(a)-7(b) show the case of in-plane θ - 2θ XRD measurements.
123 In-plane lattice constants for samples A-D were deduced to be 0.3788, 0.3775, 0.3755 and
124 0.3737 nm, respectively, using the same method as the out-of-plane case. Both out-of-plane
125 and in-plane lattice constants decreased with increasing Co/Fe ratio in $\text{Co}_x\text{Fe}_{4-x}\text{N}$, and they
126 followed Vegard's law. There was no significant difference between out-of-plane and in-plane
127 lattice constants, indicating that the lattice was almost strain-free.

128

129 **4. Conclusions**

130 We have succeeded in growing $\text{Co}_x\text{Fe}_{4-x}\text{N}$ ($0.4 < x < 2.9$) thin films epitaxially on
131 STO(001) substrates by MBE supplying solid Co, Fe, and RF- N_2 , simultaneously. We were
132 able to control the composition ratio of Co/Fe in $(\text{Co,Fe})_4\text{N}$ by changing the weight ratio of
133 Co to Fe flakes in the crucible. The lattice constants of the grown films decreased with

134 increasing Co/Fe ratio, and they were in good agreement with Vegard's law. We also
135 confirmed that the lattice was almost relaxed in the 25-nm-thick $(\text{Co,Fe})_4\text{N}$ films on
136 STO(001).

137

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181

182 **Figs. 1.** RHEED patterns of samples A-D along the azimuths of the STO[100] direction.

183

184 **Fig. 2.** Out-of-plane θ - 2θ XRD patterns of Fe₄N and samples A-D.

185

186 **Fig. 3.** In-plane θ - 2θ XRD patterns of samples A-D around $2\theta=23^\circ$.

187

188 **Fig. 4.** RBS depth profiles of Co, Fe, N, Au, Mg and O atoms in sample E.

189

190 **Fig. 5.** EDX spectra of samples A-D.

191

192 **Figs. 6.** (a) Out-of-plane lattice constants of samples A-D deduced from XRD peak positions

193 plotted as a function of $\cot\theta$. (b) Corrected out-of-plane lattice constants plotted as a function

194 of the composition ratio of Co_xFe_{4-x}N.

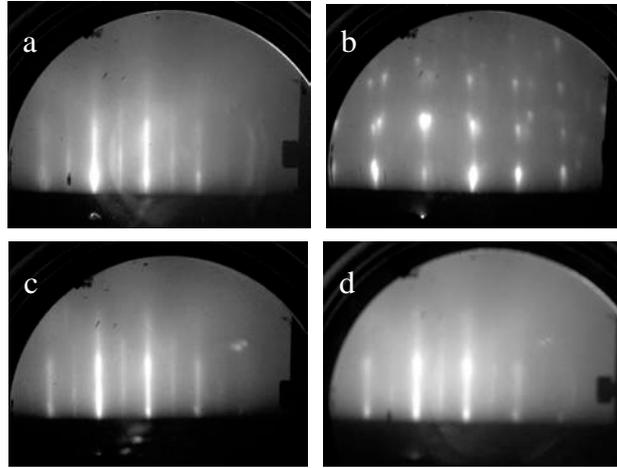
195

196 **Figs. 7.** (a) In-plane lattice constants of samples A-D deduced from XRD peak positions

197 plotted as a function of $\cot\theta$. (b) Corrected in-plane lattice constants plotted as a function of

198 the composition ratio of Co_xFe_{4-x}N.

199



Figs. 1

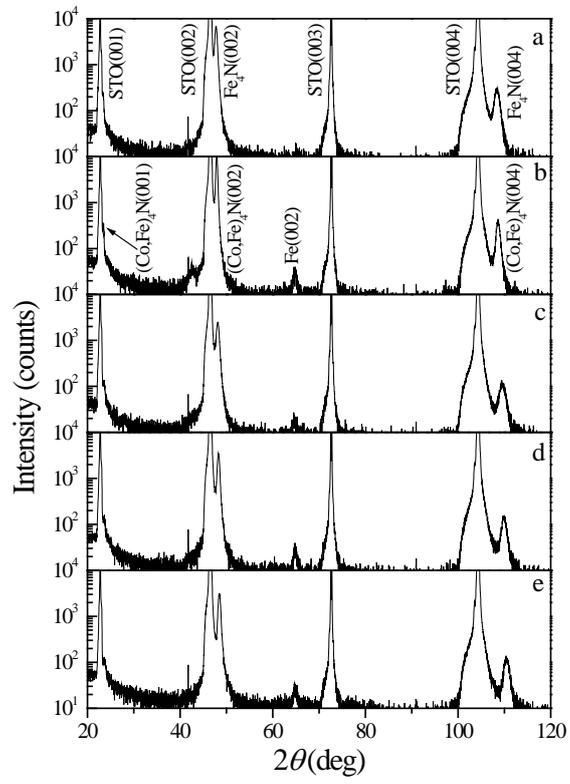


Fig. 2

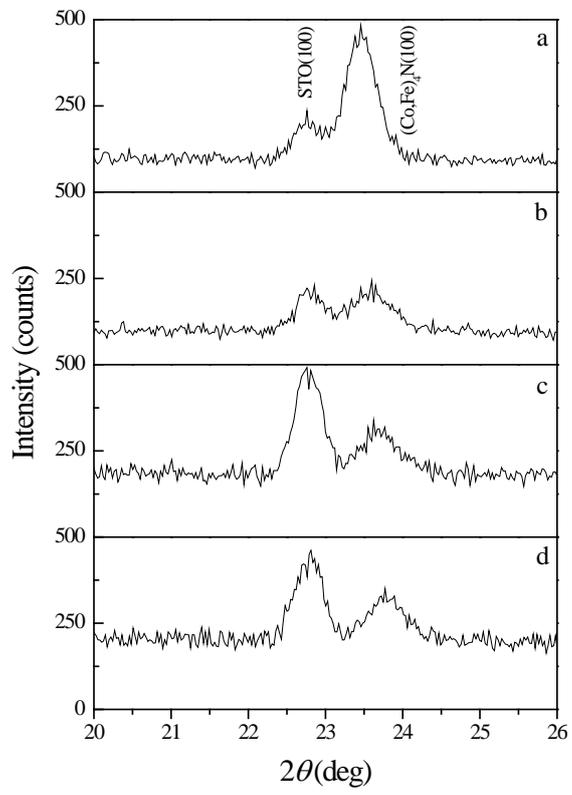


Fig. 3

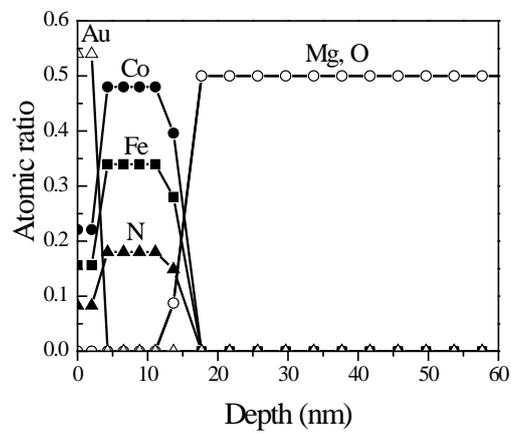


Fig. 4

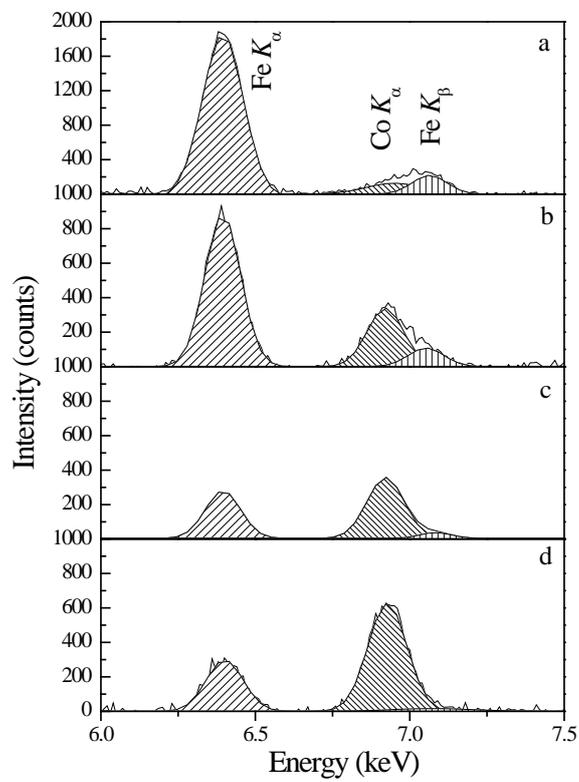
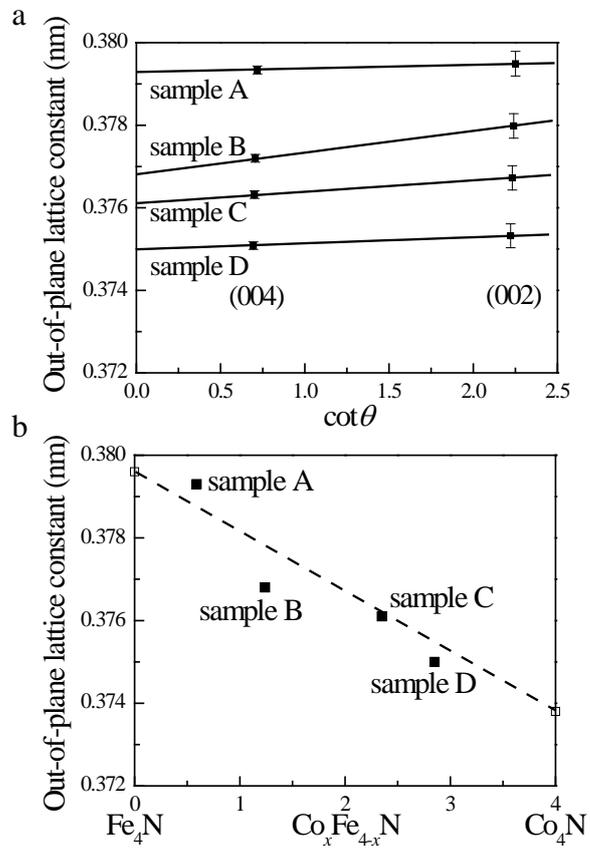
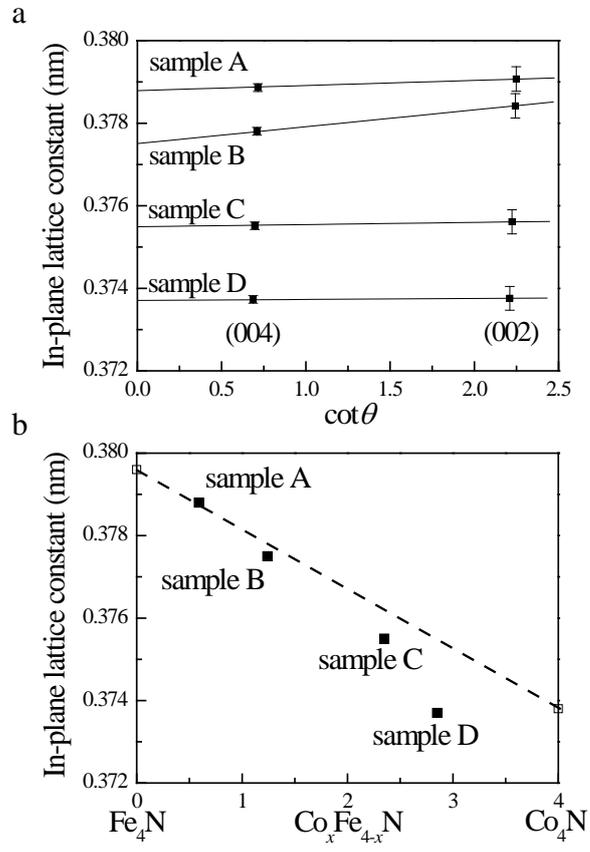


Fig. 5



Figs. 6



Figs. 7